NSN 5961-01-096-6318

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-096-6318 **Inclosure Material:** Metal **Overall Length:** 0.200 inches **Overall Diameter:** 0.710 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage, dc and 70.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 65.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 99974-st7890327 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No